



DMP3036SFG

30V P-CHANNEL ENHANCEMENT MODE MOSFET PowerDI3333-8

Product Summary

BV _{DSS}	Rds(on) Max	I _D Max Tc = +25°C
-30V	$20m\Omega @ V_{GS} = -10V$	-30A
-30 V	29mΩ @ V _{GS} = -5V	-30A

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) yet maintain superior switching performance, making it ideal for high-efficiency power-management applications.

- Backlighting
- Power-management functions
- DC-DC converters

Features and Benefits

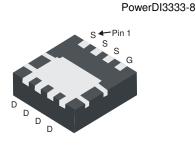
- Low RDS(ON) ensures on state losses are minimized.
- Small form factor thermally efficient package enables higher density end products.
- Occupies just 33% of the board area occupied by SO-8 enabling smaller end product.
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/104/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

 This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability. <u>https://www.diodes.com/guality/product-definitions/</u>

Mechanical Data

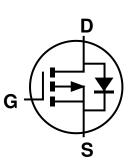
- Package: PowerDI[®] 3333-8
- Package Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
 Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 ⁽²³⁾
- Weight: 0.03 grams (Approximate)



Bottom View



Top View



Equivalent Circuit

Ordering Information (Note 4)

Ĩ	Part Number	Paakaga	Packing			
	Part Nulliber	Package	Qty.	Carrier		
	DMP3036SFG-7	PowerDI3333-8	2,000	Tape & Reel		
ſ	DMP3036SFG-13	PowerDI3333-8	3,000	Tape & Reel		

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

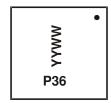
4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.



Marking Information

Site 1

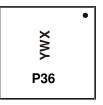
PowerDI3333-8



P36 = Product Type Marking Code YYWW = Date Code Marking YY = Last Two Digits of Year (ex: 23 = 2023) WW = Week Code (01 to 53)

Site 2:

PowerDI3333-8



P36 = Product Type Marking Code YWX = Date Code Marking Y = Year (ex: 3 = 2023) W = Week (ex: a = Week 27; z Represents Week 52 and 53) X = Internal Code (ex: U = Monday)

Date Code Kev

Year	2023	2024	2025	2026	2027	2028	2029	2030	2031	2032
Code	3	4	5	6	7	8	9	0	1	2
Week		1-26			27	7-52			53	
Code	A-Z			a-z				Z		
Internal Code	Sun		Mon	Tue	W	ed	Thu	Fri		Sat
Code	Т		U	V	1	N	Х	Y		Z

Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	VDSS	-30	V	
Gate-Source Voltage		Vgss	±25	V
Continuous Drain Current (Note 6) V_{GS} = -10V	T _A = +25°C T _A = +70°C	ID	-8.7 -7.0	A
Continuous Drain Current (Note 7) V _{GS} = -10V	Tc = +25°C T _C = +70°C	ID	-30 -25	А
Continuous Drain Current (Note 6) V _{GS} = -5V	T _A = +25°C T _A = +70°C	ID	-7.2 -5.8	А
Continuous Drain Current (Note 7) $V_{GS} = -5V$	T _C = +25°C T _C = +70°C	ID	-30 -24	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%)	I _{DM}	-80	A	
Maximum Continuous Body Diode Forward Current (Note 6)	ls	-3.6	A	
Avalanche Current (Note 7) L=0.3mH	I _{AS}	-17.5	A	
Avalanche Energy (Note 7) L=0.3mH	E _{AS}	64	mJ	

Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	0.9	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	D	137	°C/W
memai Resistance, Junction to Ambient (Note 5)	t<10s	R ₀ JA	65	°C/W
Total Power Dissipation (Note 6)		PD	2.3	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	D	55	°C/W
memai Resistance, sunction to Ambient (Note 6)	t<10s	R ₀ JA	26	°C/W
Thermal Resistance, Junction to Case (Note 7)		R _{θJC}	3.5	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	С°

Notes:

Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
 Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.
 Thermal resistance from junction to soldering point (on the exposed drain pad).

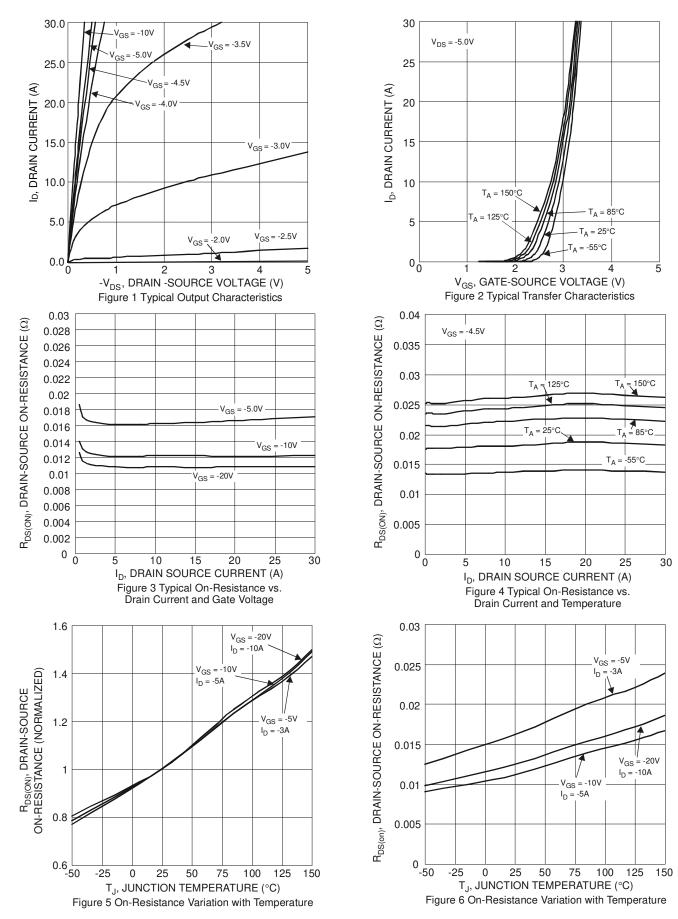


Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

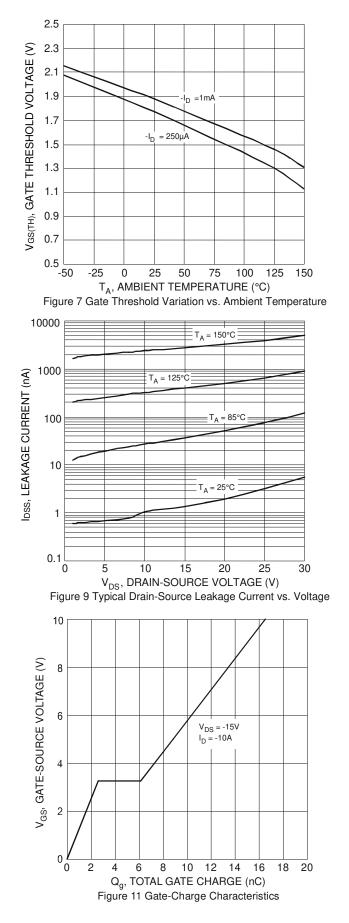
					1	
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BVDSS	-30	—	—	V	$V_{GS} = 0V, I_D = -250 \mu A$
Zero Gate Voltage Drain Current	IDSS	_	—	-1.0	μA	$V_{DS} = -30V$, $V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±100	nA	$V_{GS} = \pm 25V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	VGS(TH)	-1.0	-2.0	-2.5	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$
Static Drain-Source On-Resistance	Decient	—	13	20	mΩ	$V_{GS} = -10V, I_{D} = -8A$
Static Drain-Source On-Resistance	Rds(on)	—	18.4	29	11152	$V_{GS} = -5V, I_{D} = -5A$
Diode Forward Voltage	V _{SD}	—	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	1931	—	pF	
Output Capacitance	Coss	—	226	—	pF	Vps = -15V, Vgs = 0V, f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	168	-	pF	1 = 1.00012
Gate Resistance	Rg	_	10.9	—	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$
Total Gate Charge V _{GS} = -5V	Qg	—	8.8	-	nC	
Total Gate Charge V _{GS} = -10V	Qg	_	16.5	—	nC	
Gate-Source Charge	Qgs		2.6	—	nC	V _{DS} = -15V, I _D = -10A
Gate-Drain Charge	Q _{gd}	_	3.6	—	nC	
Turn-On Delay Time	t _{D(ON)}		8.2	—	ns	
Turn-On Rise Time	tR	_	14	—	ns	Vgs = -10V, Vdd = -15V,
Turn-Off Delay Time	tD(OFF)		65	—	ns	$R_{GEN} = 3\Omega$, $I_D = -10A$
Turn-Off Fall Time	tF		31.6	—	ns	
Reverse Recovery Time	trr	_	9.3	—	ns	
Reverse Recovery Charge	Q _{RR}		12.2	—	nC	IF = -8A, di/dt = 500A/μs

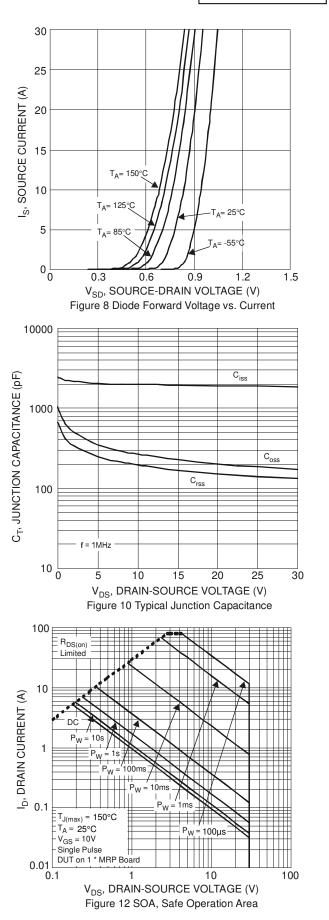
Notes:8. Short duration pulse test used to minimize self-heating effect.9. Guaranteed by design. Not subject to product testing.



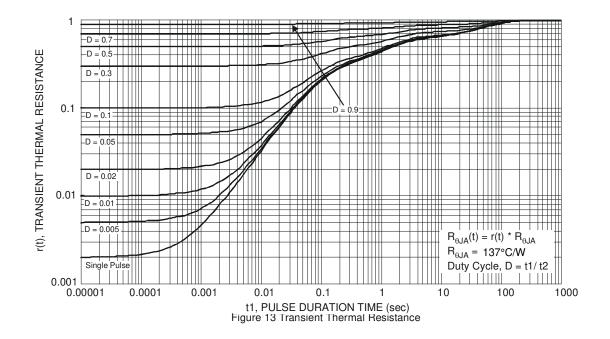








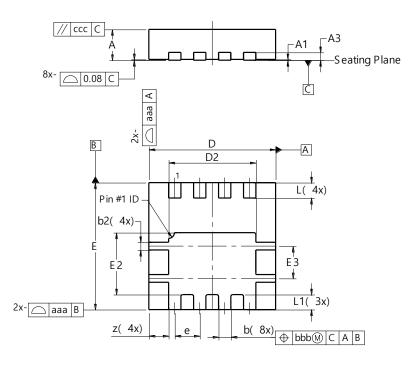






Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.



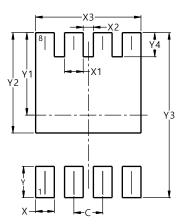
PowerDI3333-8

	PowerDI3333-8						
Dim	Min	Max	Тур				
Α	0.75	0.85	0.80				
A1	0.00	0.05	0.02				
A3	-	-	0.203				
b	0.27	0.37	0.32				
b2	-	-	0.20				
D	3.25	3.35	3.30				
D2	2.22	2.32	2.27				
Е	3.25	3.35	3.30				
E2	1.56	1.66	1.61				
E3	0.79	0.89	0.84				
е	-	-	0.65				
L	0.35	0.45	0.40				
L1	-	-	0.39				
z	-	-	0.515				
aaa	0.25						
bbb	0.10						
CCC	0.10						
All I	Dimens	sions ir	n mm				

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

PowerDI3333-8



Dimensions	Value (in mm)
С	0.650
Х	0.420
X1	0.420
X2	0.230
X3	2.370
Y	0.700
Y1	1.850
Y2	2.250
Y3	3.700
Y4	0.540



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